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# Water Infrared Spectrum at the interface with silicon and hydrogen-terminated silicon surfaces using molecular dynamics approach



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School of Biosystems & Food Engineering

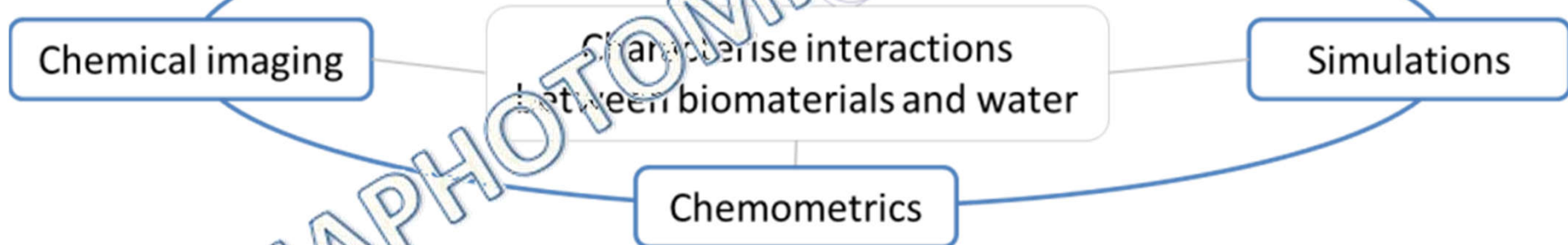
AQUAPHOTOMICS: UNDERSTANDING WATER in BIOLOGY  
2nd INTERNATIONAL SYMPOSIUM

# Biowater Project



European Research Council

## BioWater

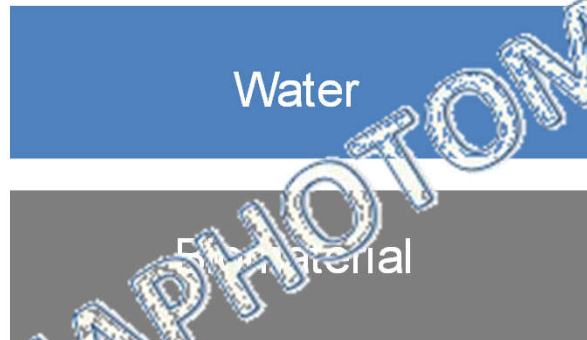
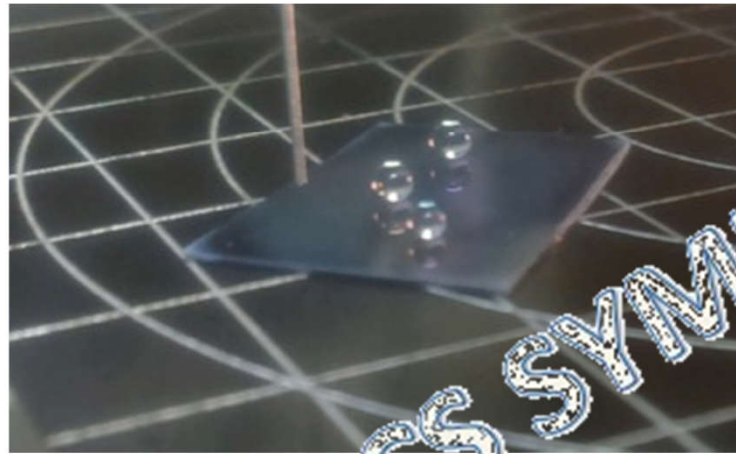


<http://cms.ucd.ie/biowater/>

Twitter: #BioWaterERC

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# Overview



Biomaterial-water interface  
*not very well understood<sup>1</sup>*

How does the water structure change depending of the material?

Is it possible explain the hydrophobic effect from these changes in the structure?

1. Bunkin, N., Ignatiev, P., Kozlov, V., Shkirin, A., Zakharov, S., Zinchenko, A. (2013) 'Study of the Phase States of Water Close to Nafion Interface', *Water*, 4(Mauritz 2004), 129–154

# Biowater Project



Sindhuraj Mukherjee

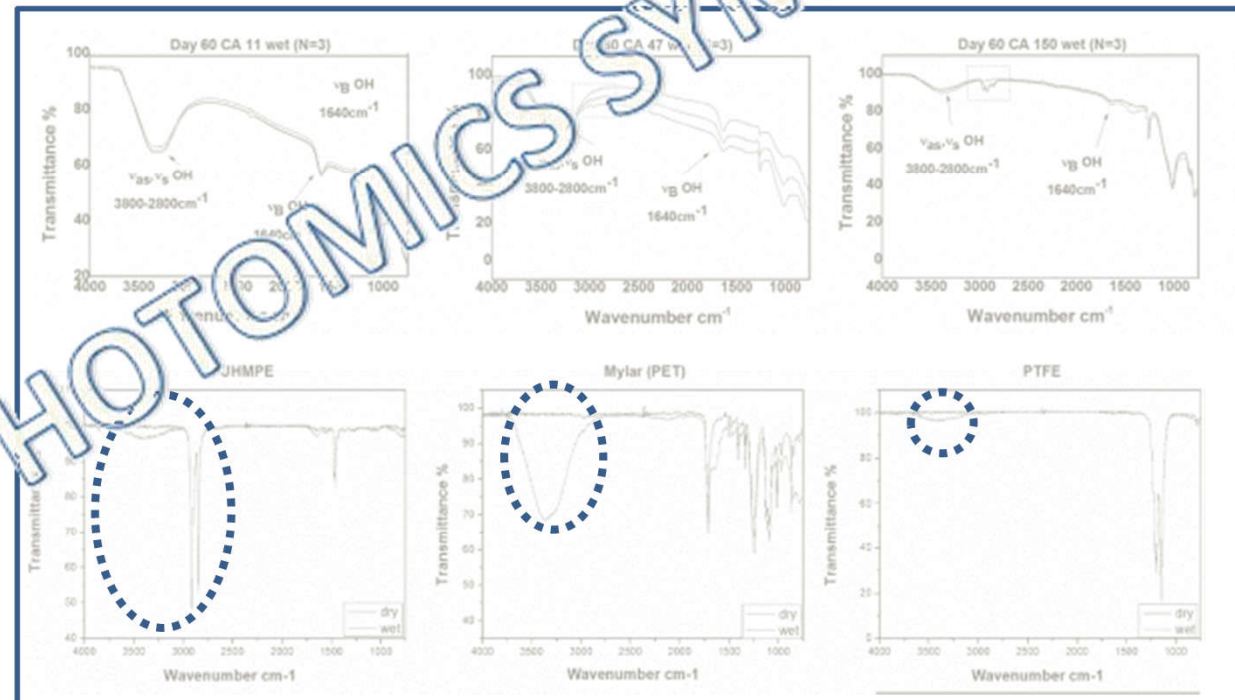
## Interactions: polymer biomaterials & water

### Polymers

- UHMPE
- PET
- PTFE
- PLLA
- P3HB
- Silicones
- HMDSO coatings

### Measurements

- ATR-FTIR
- Contact angle



# Simulation of water in heterogeneous environments

Simulation liquid, supercooled and  
ice water

# Theoretical Background



Molecular Dynamics Simulation

$$F_i = m_i a_i$$

$$-\frac{dU}{dr_i} = m_i \frac{d^2 r_i}{dt^2}$$

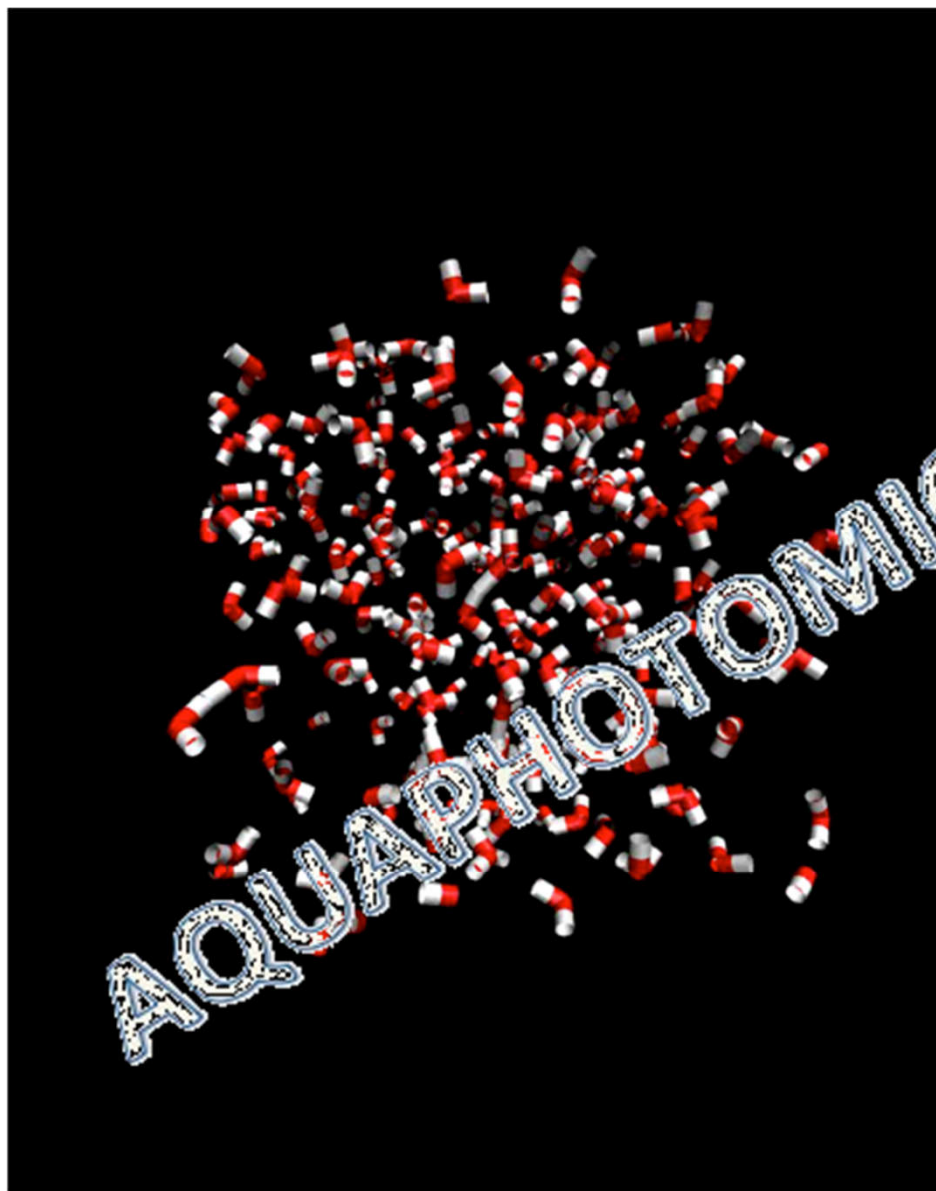
calculate the time evolution of the position (Trajectory)

$$r_{i+1} = r_i + \frac{\partial r_i}{\partial t} \delta t + \frac{1}{2!} \frac{\partial^2 r_i}{\partial t^2} \delta t^2 + \frac{1}{3!} \frac{\partial^3 r_i}{\partial t^3} \delta t^3 + \dots$$

$$v = \frac{dr_i}{dt}$$

$$a_i = \frac{d^2 r_i}{dt^2} = -\frac{1}{m} \frac{dV}{dr_i}$$

# Water Model Parameters



## Water Models

$$V^{\text{intra}} = \frac{k_b}{2} [(r_{\text{OH}_1} - r_{\text{OH}}^0)^2 + (r_{\text{OH}_2} - r_{\text{OH}}^0)^2] + \frac{k_a}{2} (\theta_{\angle \text{HOH}} - \theta_{\angle \text{HOH}}^0)^2,$$

$$V^{\text{inter}} = \sum_{i,j} \left\{ 4\epsilon_{ij} \left[ \left( \frac{\sigma_{ij}}{r_{ij}} \right)^{12} - \left( \frac{\sigma_{ij}}{r_{ij}} \right)^6 \right] + \frac{q_i q_j}{r_{ij}} \right\},$$

	SPC/Fw <sup>1</sup>
r(OH), Å	1.012
HOH, deg	113.24
Ka·10 <sup>-3</sup> , kcal·rad <sup>-2</sup> ·mol <sup>-1</sup>	75.90
Kb, kcal·Å <sup>-2</sup> ·mol <sup>-1</sup>	1059.162
q(O)	-0.82
q(H)	0.41
σ(OO), Å	3.165492
ε(OO), kcal·mol <sup>-1</sup>	0.1554253

1. Y. Wu, H. L. Tepper and G. A. Voith, Flexible simple point-charge water model with improved liquid state properties, J. Chem. Phys. **124** (2006) 024503

# Theoretical Background



Velocity Autocorrelation Function

$$C_{vv}(t) = \frac{1}{N} \sum_{i=1}^N \langle v_i(t) \cdot v_0(t) \rangle$$



DOS (power spectra)

Dipole Autocorrelation Function

$$\langle M(t) \cdot M(0) \rangle = \left\langle \sum_{j=1}^n e_j r_j(t) \cdot \sum_{j=1}^n e_j r_j(0) \right\rangle$$



Infrared Spectra

$$I(\omega) \propto \int_0^{\infty} \langle M(t) \cdot M(0) \rangle \cos(\omega t) dt$$

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# Water-Ice VACF

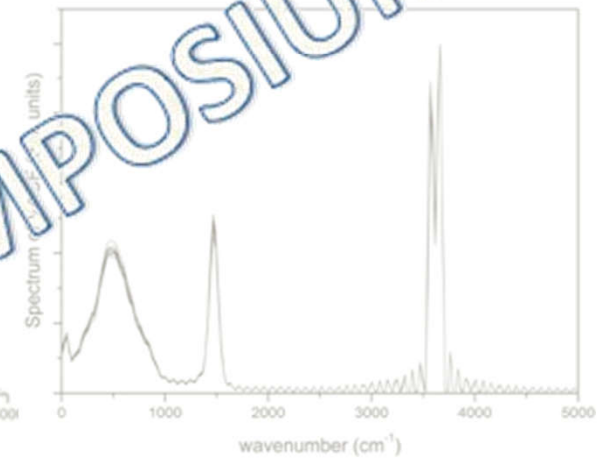
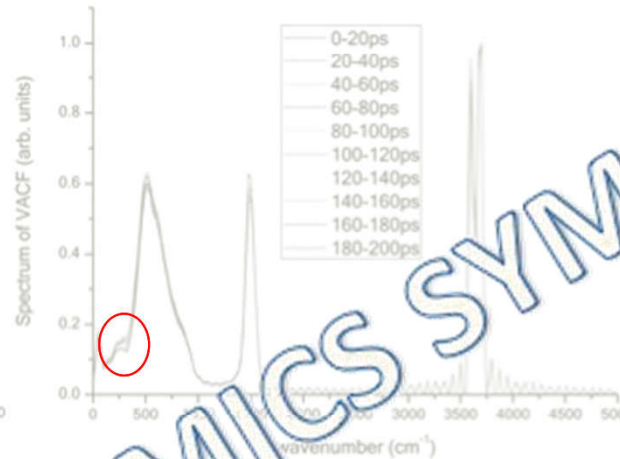
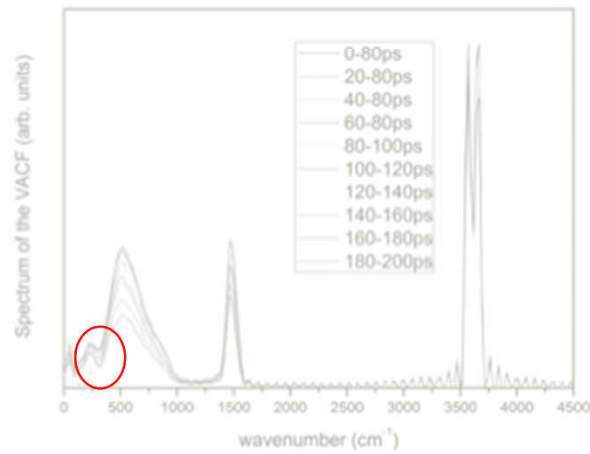


ICE (220K)

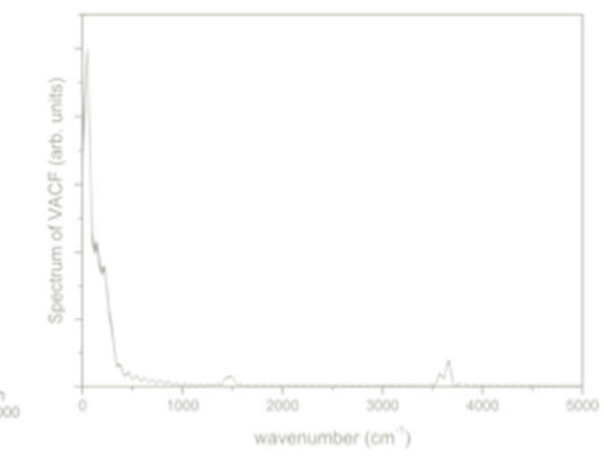
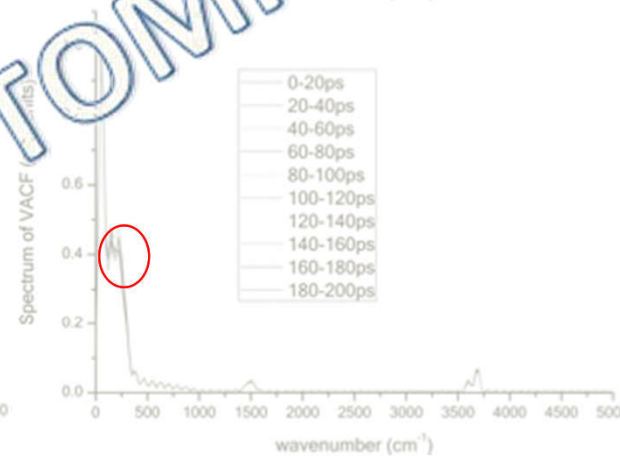
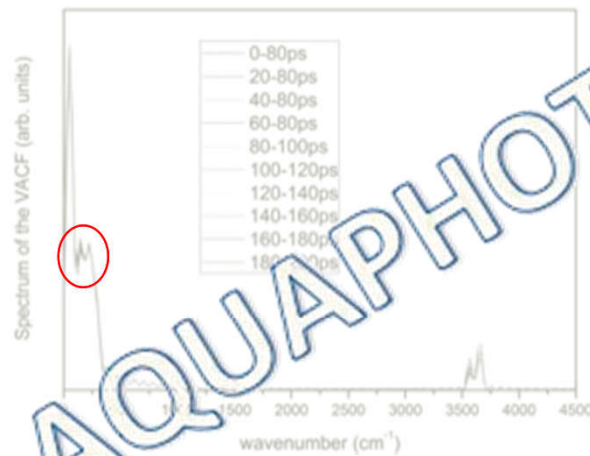
H<sub>2</sub>O (220K)

H<sub>2</sub>O (300K)

H



O

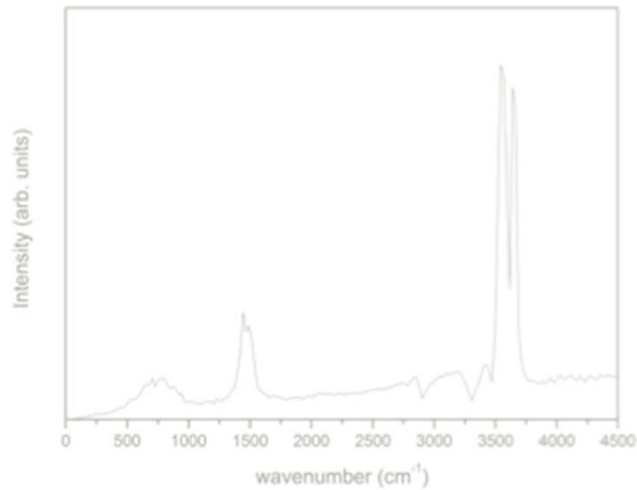


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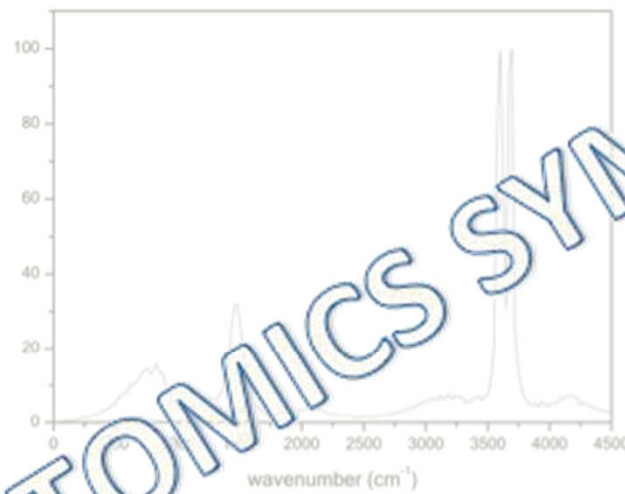
# Water-Ice IR



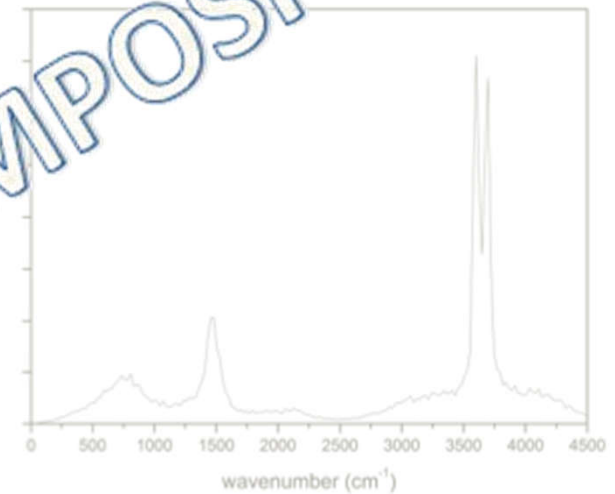
ICE (220K)



H<sub>2</sub>O (220K)



H<sub>2</sub>O (300K)

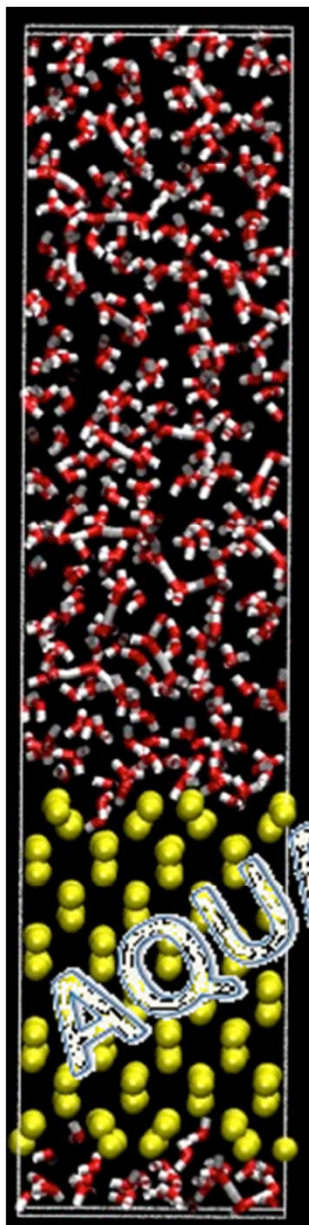


	Ice (220K)	H <sub>2</sub> O (220K)	H <sub>2</sub> O (300K)
$\nu_s$ (s, n-sym)	3639-3544	3696-3600	3696-3600
$\nu_s$	1443-1490	1481	1481

# Simulation of water in heterogeneous environments

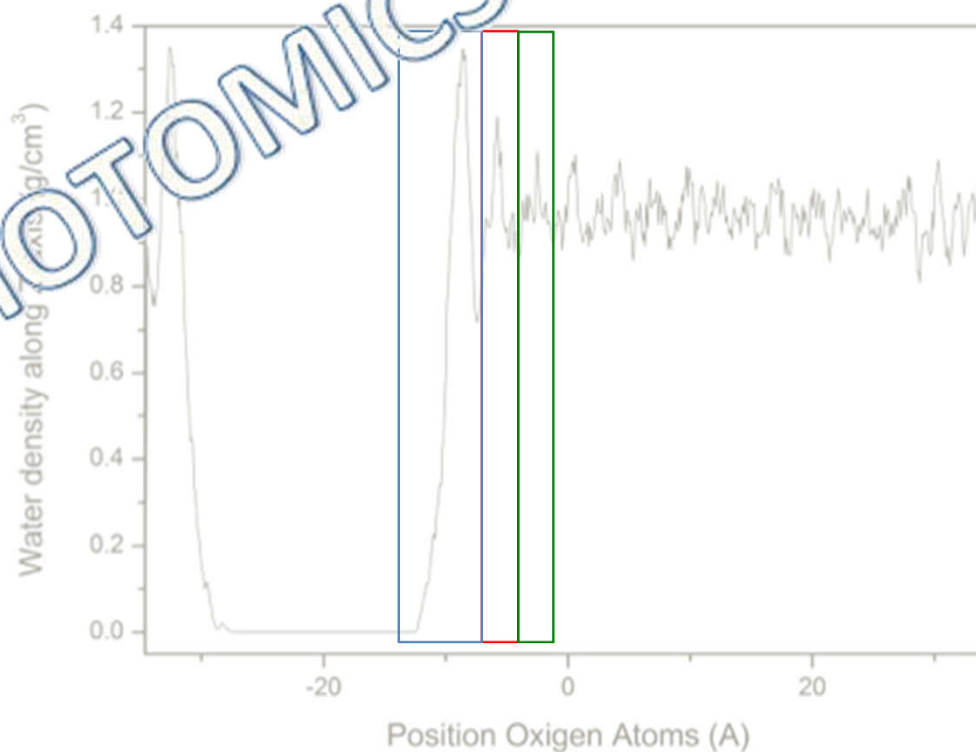
Simulation water silicon interface

# Water Silicon Interface



Box size: 15.566 Å x 15.566 Å x 69.0 Å  
378 H<sub>2</sub>O molecules  
256 Si atoms

Simulation parameters :  
ensemble nvt evans, velocity verlet  
200 ps,  $t_{\text{step}}$  0.1fs,  $t_{\text{sampling}}$  2 fs, 300K

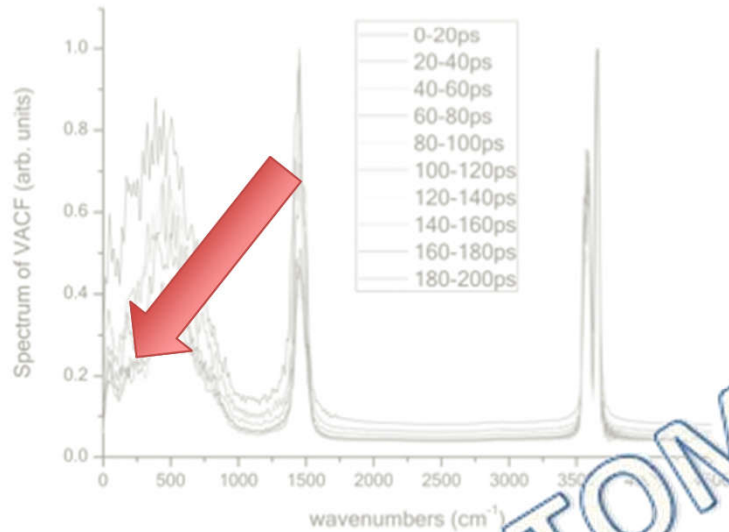


# Water Silicon Interface VACF

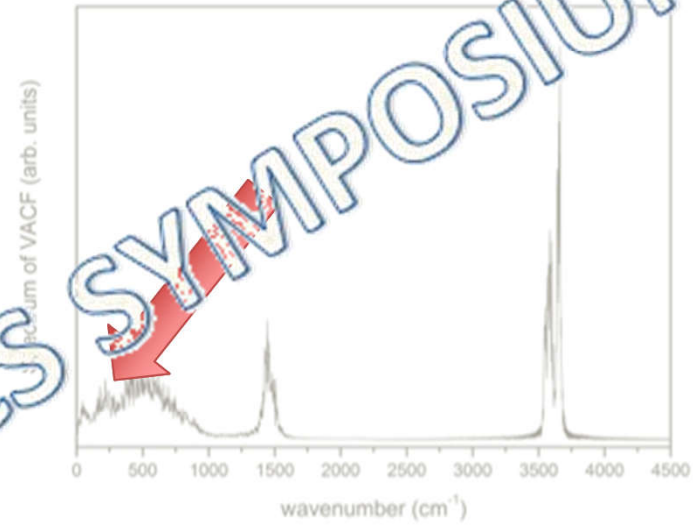


H

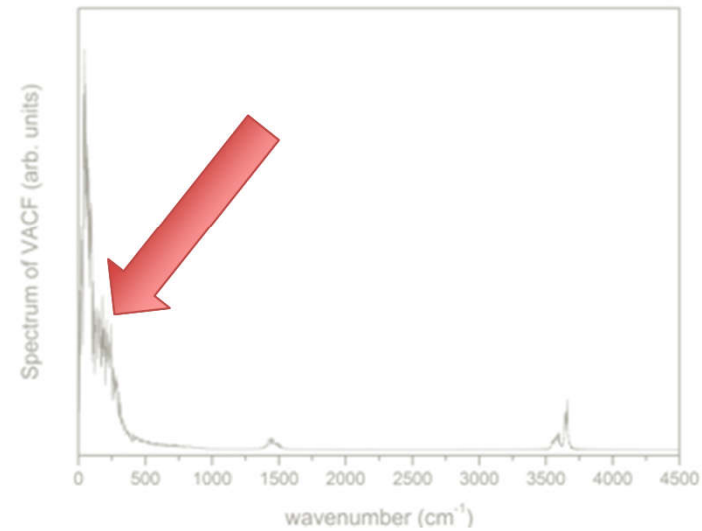
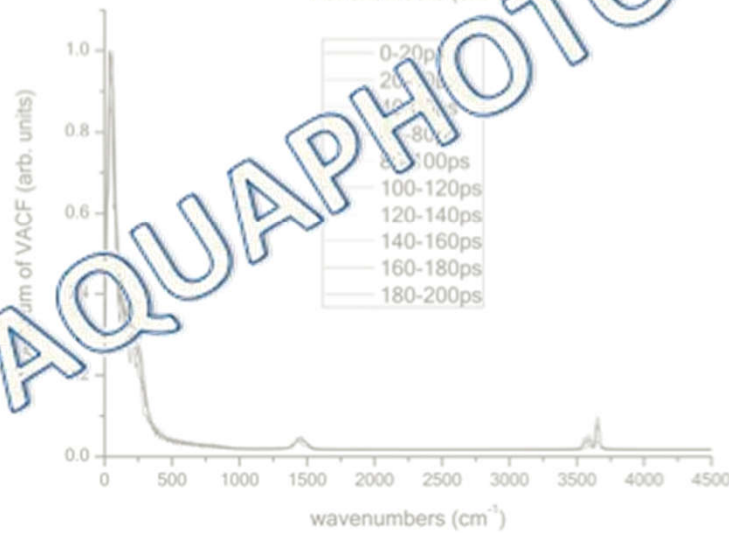
After 200ps



After 2 ns



O



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# Theoretical Background



Dipole Autocorrelation Function  $\langle M(t) \cdot M(0) \rangle = \left\langle \sum_{j=1}^n e_j r_j(t) \cdot \sum_{j=1}^n e_j r_j(0) \right\rangle$

Electrical Flux-Flux Autocorrelation Function

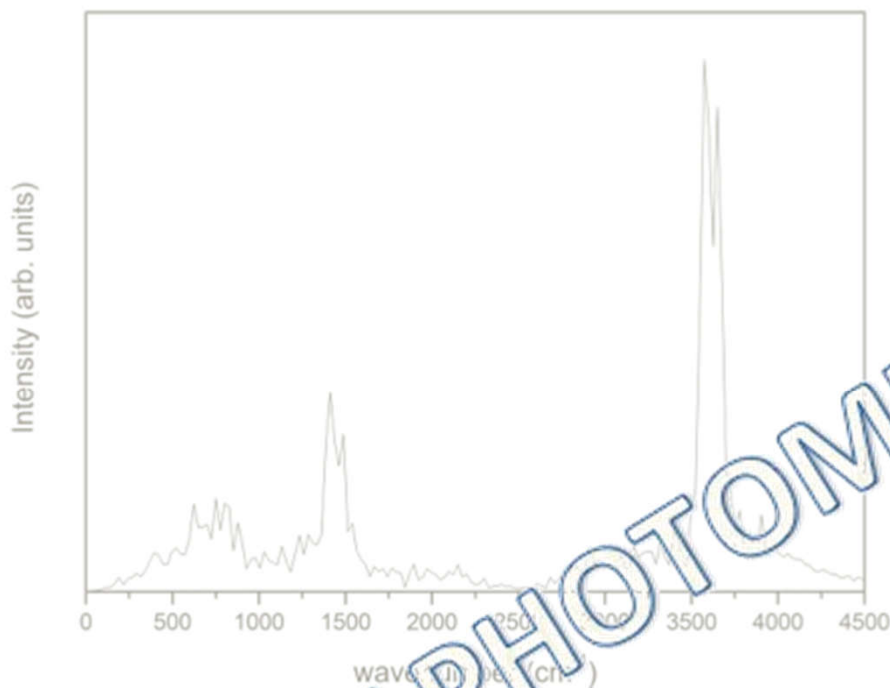
$$\left\langle \frac{dM(t)}{dt} \cdot \frac{dM(0)}{dt} \right\rangle = \left\langle \sum_{j=1}^n e_j \frac{dr_j(t)}{dt} \cdot \sum_{j=1}^n e_j \frac{dr_j(0)}{dt} \right\rangle = \left\langle \sum_{j=1}^n e_j v_j(t) \cdot \sum_{j=1}^n e_j v_j(0) \right\rangle$$

$$\begin{aligned} S(\omega) &\propto \int_0^{\infty} \left\langle \frac{dM(t)}{dt} \cdot \frac{dM(0)}{dt} \right\rangle \cos(\omega t) dt = \\ &= \int_0^{\infty} \left\langle \sum_{j=1}^n e_j v_j(t) \cdot \sum_{j=1}^n e_j v_j(0) \right\rangle \cos(\omega t) dt \end{aligned}$$

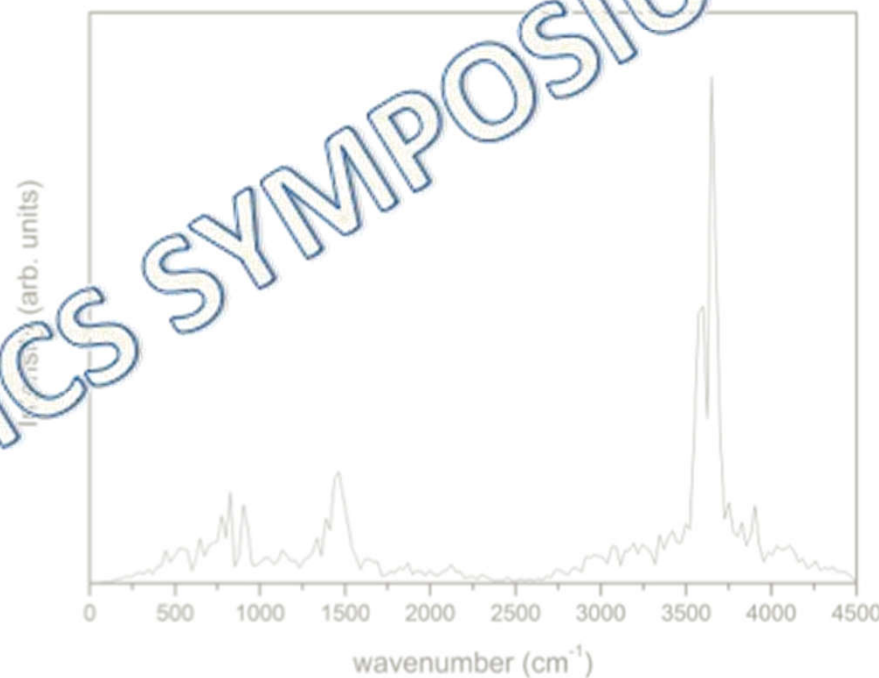
# Water Silicon Interface IR



After 200ps



After 2 ns



	After 200ps	After 2ns
$\nu_s$ (asym-sym)	3649-3573	3649-3579
$\nu_b$	1437-1480	1462

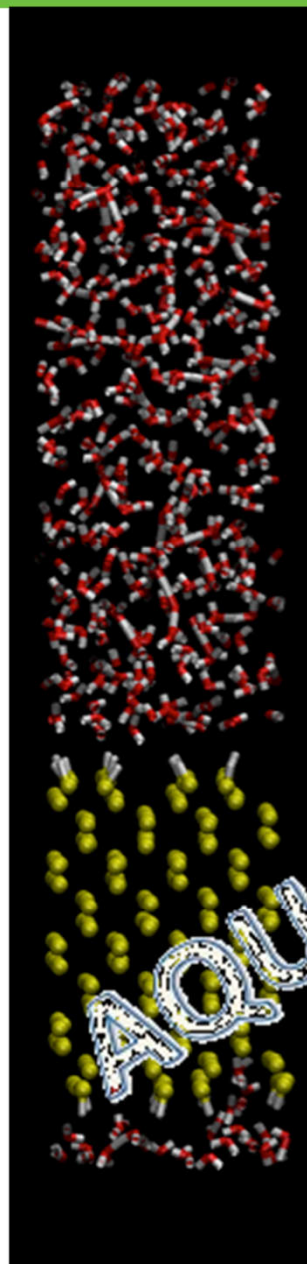
	Ice (220K)	H <sub>2</sub> O (220K)	H <sub>2</sub> O (300K)
$\nu_s$ (asym-sym)	3639-3544	3696-3600	3696-3600
$\nu_b$	1443-1490	1481	1481

# Simulation of water in heterogeneous environments

Simulation hydrogen-terminated  
silicon water interface

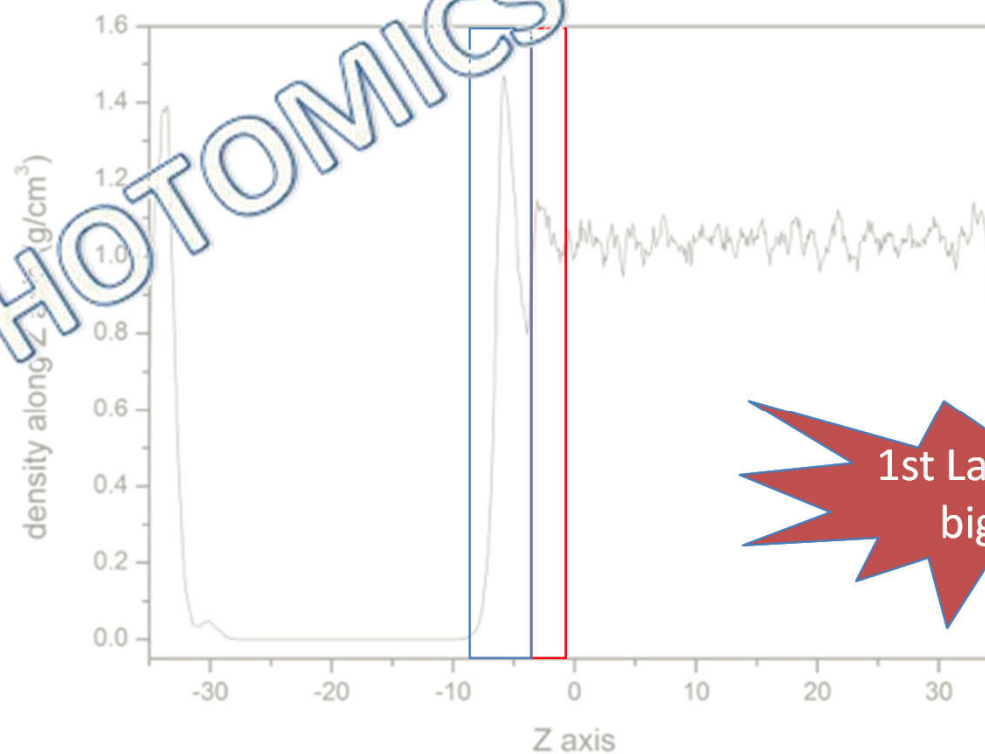


# Water Silicon-Hydrogen Interface



Box size: 15.566 Å x 15.566 Å x 69.0 Å  
378 H<sub>2</sub>O molecules  
256 Si atoms + 32 H atoms

Simulation parameters :  
ensemble nvt evans, velocity verlet  
200 ps,  $t_{\text{step}}$  0.1fs,  $t_{\text{sampling}}$  2 fs, 300K

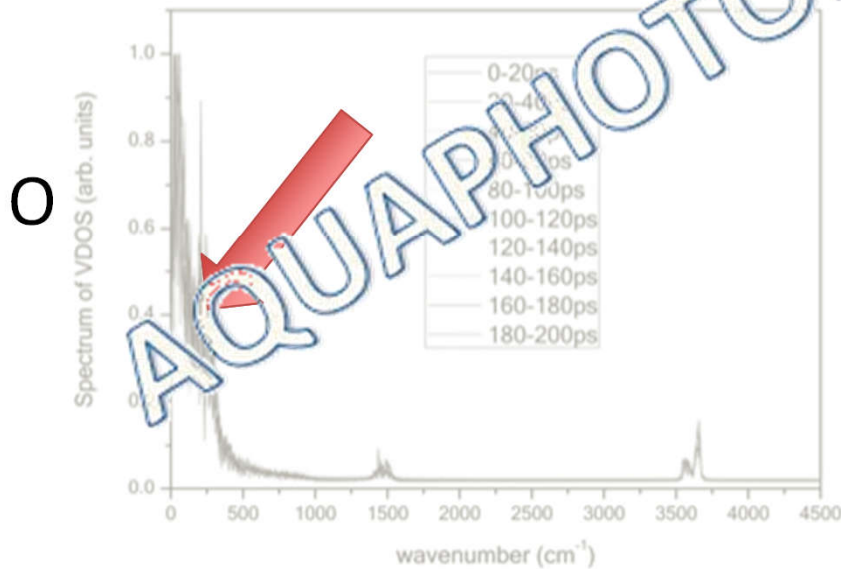
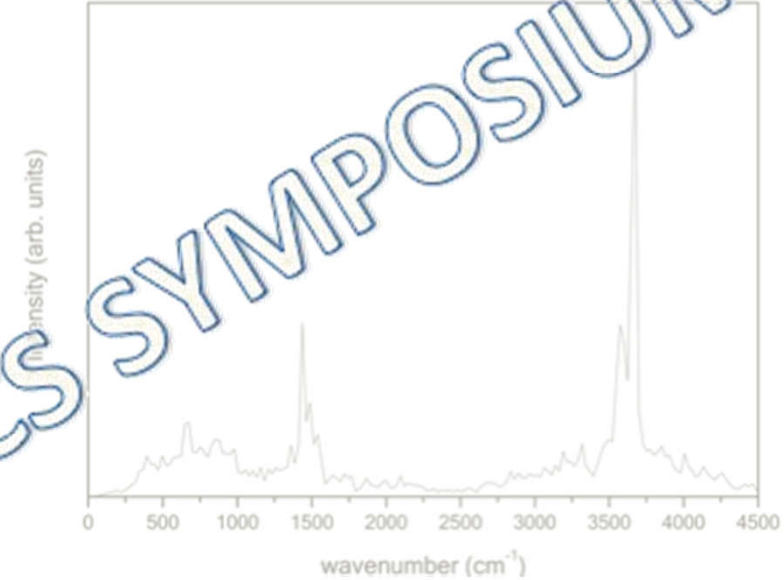
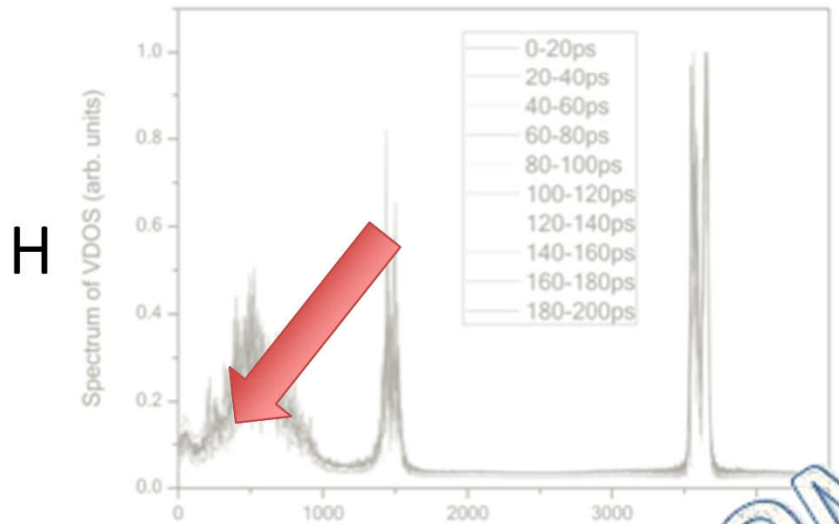


# Water Silicon-Hydrogen Interface



VACF

mid-IR



	Si-H+H <sub>2</sub> O	Si + H <sub>2</sub> O
$\nu_s$ (asym-sym)	3673-3573	3649-3573
$\nu_b$	1437-1487	1437-1480

	Ice (220K)	H <sub>2</sub> O (220K)	H <sub>2</sub> O (300K)
$\nu_s$ (asym-sym)	3639-3544	3696-3600	3696-3600
$\nu_b$	1443-1490	1481	1481

# Final Remarks



Liquid, Supercooled and Ice Water Simulations:

- Differences in librational bands for VACF and IR
- Movements to lower wavenumbers when water acquires structure.

Silicon with Water System:

- Density water variation along Z axis gives the different solvation layers.
- 1st solvation layer is bigger for Hydrogen terminal surface. Hydrophobic effect.

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# Final Remarks



## Silicon with Water System:

- 1st solvation layer power spectra after 200ps show some water organisation similar to ice water.
- 1st solvation IR spectra , achieved through the electrical flux-flux approach, confirms the organisation of water in a halfway between liquid and ice water.

## Future plans:

- Simulation of Hydroxyl-terminated Silicon surface.
- Protein water interface

# Acknowledgments



*Niall English*



*Eife Gowen*



Thanks for your attention

